NSN 5961-01-295-4540

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View Online at https://aerobasegroup.com/nsn/5961-01-295-4540 **Inclosure Material:** Ceramic **Overall Length:** 0.280 inches **Terminal Length:** Between 0.250 inches and 0.370 inches **Overall Height:** Between 0.030 inches and 0.085 inches **Overall Width:** Between 0.240 inches and 0.260 inches **Function For Which Designed:** Switching **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Quality assurance level tx **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.4 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 14 pin **Specification Data:** 81349-mil-s-19500/558 government specification Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

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